INTERCONNECTIONS FOR FLIP-CHIP USING LEAD-FREE SOLDERS AND HAVING REACTION BARRIER LAYERS

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ABSTRACT OF THE INVENTION

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7 An interconnection structure suitable for flip-chip 8 attachment of microelectronic device chips to packages, 9 comprising a two, three or four layer ball-limiting 10 composition including an adhesion/reaction barrier 11 layer, and having a solder wettable layer reactive with 12 components of a tin-containing lead free solder, so that the solderable layer can be totally consumed 13 14 during soldering, but a barrier layer remains after 15 being placed in contact with the lead free solder 16 during soldering. One or more lead-free solder balls is 17 selectively situated on the solder wetting layer, the lead-free solder balls comprising tin as a predominant 18 19 component and one or more alloying components.